

## **Application Data Sheet**

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### **Inventor Information**

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### **Application Information**

Title Line One: REFERENCE VOLTAGE GENERATION THE  
Title Line Two: CIRCUIT FOR SEMICONDUCTOR MEMORY  
Title Line Three: DEVICE, MEMORY READING CIRCUIT  
Title Line Four: INCLUDING SAME, AND ELECTRONIC  
Title Line Five: INFORMATION DEVICE INCLUDING THE SAME  
Total Drawing Sheets: 14  
Formal Drawings?: Yes  
Application Type: Utility  
Docket Number: 299002054200

### **Representative Information**

Representative Customer Number: 25226

## **Continuity Information**

This application is a:

> Application One:

Filing Date:

which is a:

>>Application Two:

Filing Date:

which is a:

>>>Application Three:

Filing Date:

## **Prior Foreign Applications**

Foreign Application One:

2001-057499

Filing Date:

March 1, 2001

Country:

Japan

Priority Claimed:

Yes